

RoHS

COMPLIANT

N-Channel 60 V (D-S) Super Junction MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	R _{DS(on)} (mΩ)(Typ.)	I _D (A) ^a	Q _g (Typ.)		
60	0.8at V _{GS} = 10 V	305	127nC		

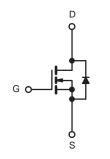
FEATURES

- **DT-SJ Power MOSFET**
- 100 % Rg and UIS Tested •
- Low On-Resistance

APPLICATIONS

- High-Efficiency DC-DC Converters
- Switching Voltage Regulators ٠
- Motor Drivers •





N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)					
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	60	V	
Gate-Source Voltage		V _{GS} ± 20		V	
Continuous Drain Current (T _{.1} = 150 °C) ^a	T _C = 25 °C	I	305		
	T _C = 100 °C	I _D	200	Α	
Pulsed Drain Current ^b		I _{DM}	900		
Single Pulse Avalanche Energy		E _{AS}	545	mJ	
Maximum Power Dissipation ^c	T _C = 25 °C	Pn	265	W	
	T _C = 100 °C	۰D	106	vv	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	- 55 to +150			
Soldering Recommendations (Peak Temperature)		260			

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^d	t ≤ 10 s	R _{thJA}	-	50	°C/W
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	-	0.47	0/11

Notes

- a. Calculated continuous current based on maximum allowablejunction temperature.
- b. Repetitive rating; pulse width limited by max. junction temperature.
- c. Pd is based on max. junction temperature, using junction-case thermal resistance.
- d. The value of ReJA is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with Ta=25 °C.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static				1		
Drain-Source Breakdown Voltage	V_{DS} $V_{GS} = 0 V, I_D = 250 \mu A$		60	-	-	v
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	2	-	4	v
Gate-Body Leakage	I _{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V	-	-	± 100	nA
		$V_{DS} = 60 V, V_{GS} = 0 V$	-	-	1	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$		-	100	μA
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \geq 10~V,~V_{GS} = 10~V$	305	-	-	А
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 50 \text{ A}$	-	0.8	0.96	mΩ
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 5 V, I_{D} = 50 A$	-	63	-	S
Dynamic ^b	· · · · · · · · · · · · · · · · · · ·					
Input Capacitance	C _{iss}		-	7370	-	pF
Output Capacitance	C _{oss}	$V_{GS} = 0 V, V_{DS} = 30 V, f = 1 MHz$	-	3230	-	
Reverse Transfer Capacitance	C _{rss}		-	160	-	
Total Gate Charge ^c	Qg		-	127	-	nC
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 50 \text{ A}$	-	22.6	-	
Gate-Drain Charge ^c	Q _{gd}		-	28	-	
Gate Resistance	R _g	f = 1 MHz	-	2.8	-	Ω
Turn-On Delay Time ^c	t _{d(on)}		-	23	-	
Rise Time ^c	t _r	$V_{DD} = 30 \text{ V}, \text{ R}_{g} = 3 \Omega$	-	18	-	ns
Turn-Off Delay Time ^c	t _{d(off)}	$I_{\rm D} = 50 \text{ A}, V_{\rm GEN} = 10 \text{ V},$	-	75	-	
Fall Time ^c	t _f		-	24	-	
Drain-Source Body Diode Ratings an	nd Characteris	stics ^b (T _C = 25 °C)			•	
Continuous Source Current	I _S	T _C = 25 °C	-	-	305	А
Pulsed Source Current	I _{SM}		-	-	300	А
Forward Voltage ^a	V _{SD}	$I_F = 1 \text{ A}, V_{GS} = 0 \text{ V}$	-	-	1.2	V
Reverse Recovery Time	t _{rr}	L = 50 A di/dt = 100 A/::-	-	45	-	ns
Reverse Recovery Charge	Q _{rr}	$I_F = 50$ A, di/dt = 100 A/µs	-	180	-	nC

Notes

a. Pulse test; pulse width $\leq 300~\mu\text{s},~\text{duty}~\text{cycle} \leq 2~\%.$

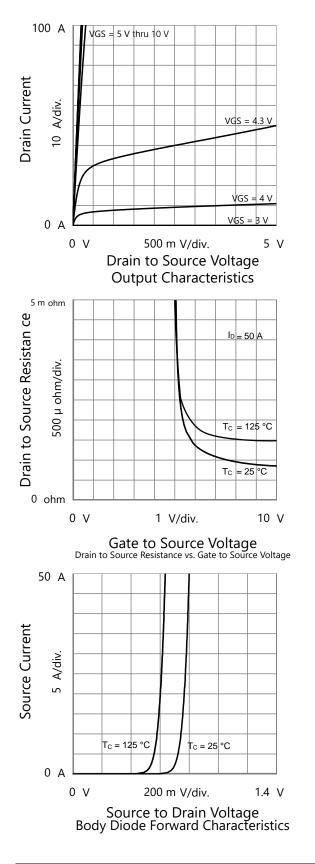
b. Guaranteed by design, not subject to production testing.

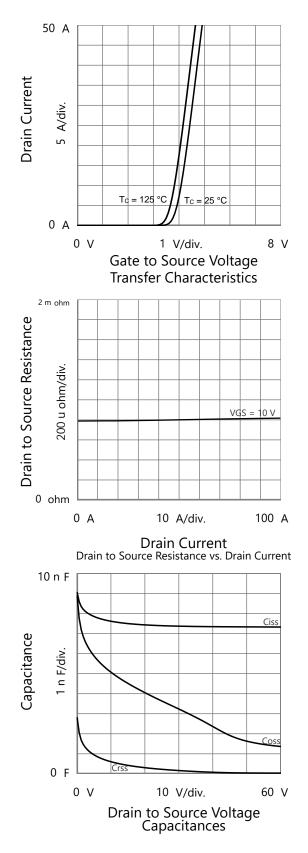
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



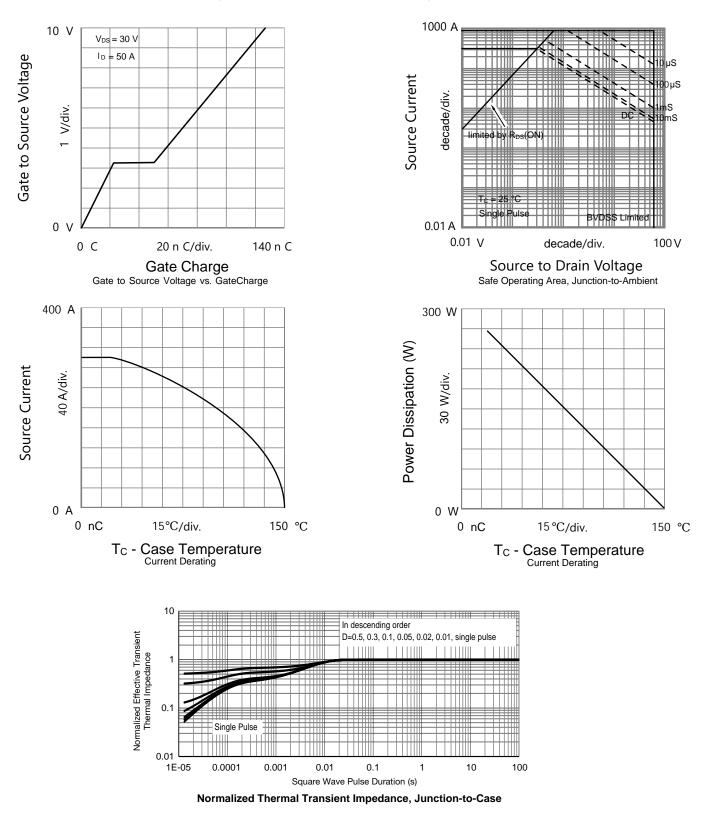
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



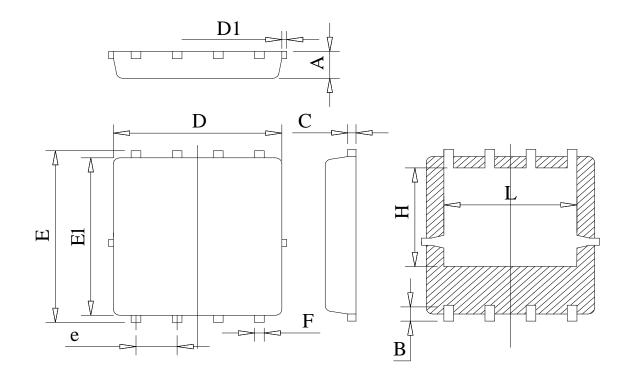




TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



DFN5*6-8L PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

Unit : mm			
Symbol	Min	Тур	Max
А	0.78	0.95	1.12
В	0.45	0.58	0.78
С	0.18	0.254	0.36
D	4.70	5.20	5.45
D1			0.18
Е	5.85	6.05	6.25
E1	5.38	5.55	5.98
e	1.15	1.27	1.40
F	0.18	0.30	0.52
Н	3.25	3.47	3.70
L	3.75	4.00	4.25



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